



DIO2031/2032/2033/2034/2036

500 μ A, 6MHz, Rail-to-Rail I/O CMOS Operational Amplifiers

Features

- Supply Voltage Range: 2.5V to 5.5V
- Low Supply Current: 500 μ A Typically
- Rail-to-Rail Input and Output
- 6MHz High Gain-Bandwidth Product
- High Slew Rate: 3.6V/ μ s
- Settling Time to 0.1% with 2V Step: 2.1 μ s
- Overload Recovery Time: 0.9 μ s
- Packages:
 - DIO2031 Available in: SOT23-5/SOIC-8
 - DIO2032 Available in:
SOIC-8/MSOP-8/TSSOP-8
 - DIO2033 Available in: SOT23-6/SOIC-8
 - DIO2034 Available in: TSSOP-14/SOIC-14
 - DIO2036 Available in: QFN4*4-20

Applications

- Audio Output
- Sensor Interface
- Active Filters
- A/D Converters
- Cellular and Cordless Phones
- Laptops and PDAs
- Photodiode Amplification
- Battery-Powered Instrumentation

Descriptions

The DIO2031 (single), DIO2032 (dual), DIO2033 (single with shutdown), DIO2034 (quad) and DIO2036 (Triple) are amplifiers with very low noise, low voltage, and low power operational. The DIO2031/2/3/4/6 has a high gain-bandwidth product of 6MHz, a slew rate of 3.6V/ μ s, and a quiescent current of 500 μ A/amplifier at 5V typically.

The DIO2031/2/3/4/6 is designed to provide optimal performance in low voltage and low noise systems. All these chips provide rail-to-rail output swing into heavy loads. The input common-mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for DIO2031/2/3/4/6.

The DIO2033 has a power-down disable feature that reduces the supply current to 90nA individually.

They are specified over the extended industrial temperature range (-40 $^{\circ}$ C to +125 $^{\circ}$ C). The operating range is from 2.5V to 5.5V.

Ordering Information

Order Part Number	Top Marking		T _A	Package	
DIO2031ST5	YWXH	RoHS/Green	-40 to +125 $^{\circ}$ C	SOT23-5	Tape & Reel, 3000
DIO2031SO8	DIO2031	RoHS/Green	-40 to +125 $^{\circ}$ C	SOIC-8	Tape & Reel, 2500
DIO2032SO8	DIO2032	RoHS/Green	-40 to +125 $^{\circ}$ C	SOIC-8	Tape & Reel, 2500
DIO2032MP8		RoHS/Green	-40 to +125 $^{\circ}$ C	MSOP-8	Tape & Reel, 3000
DIO2032TP8		RoHS/Green	-40 to +125 $^{\circ}$ C	TSSOP-8	Tape & Reel, 3000
DIO2033SO8	DIO2033	RoHS/Green	-40 to +125 $^{\circ}$ C	SOIC-8	Tape & Reel, 2500
DIO2033ST6	YWXM	RoHS/Green	-40 to +125 $^{\circ}$ C	SOT23-6	Tape & Reel, 3000
DIO2034SO14	DIO2034	RoHS/Green	-40 to +125 $^{\circ}$ C	SOP-14	Tape & Reel, 2500
DIO2034TP14		RoHS/Green	-40 to +125 $^{\circ}$ C	TSSOP-14	Tape & Reel, 2500
DIO2036QN20	DIO2036	RoHS/Green	-40 to +125 $^{\circ}$ C	QFN4*4-20	Tape & Reel, 5000

Pin Assignments

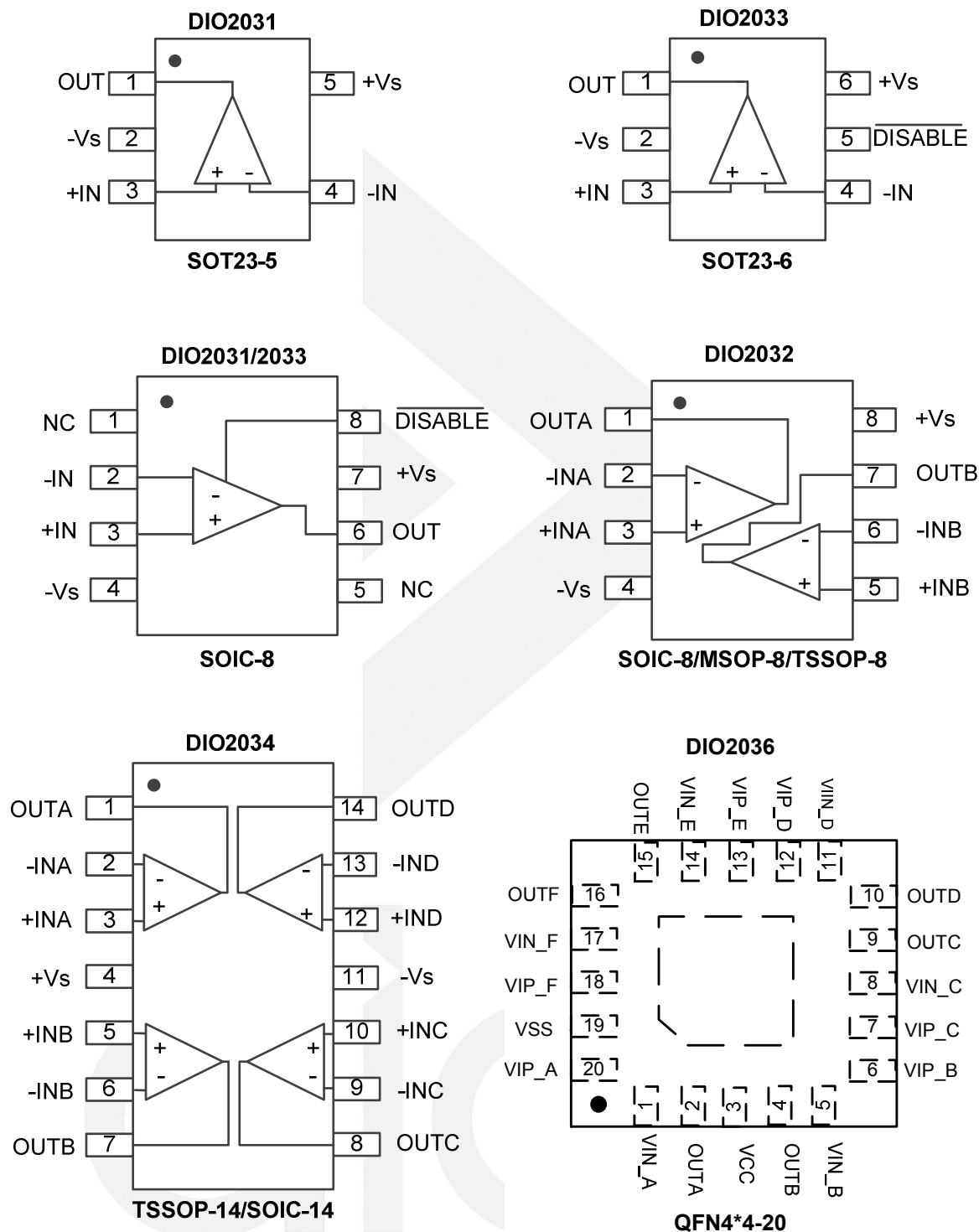


Figure 1 Pin assignment (Top View)

Pin Description

Pin name	Description
+Vs	Positive supply
-Vs	Negative supply
+IN (+INA/+INB/+INC/+IND)	Positive Input (channel A/B/C/D)
-IN (-INA/-INB/-INC/-IND)	Negative Input (channel A/B/C/D)
OUT (OUTA/OUTB/OUTC/OUTD)	Output (channel A/B/C/D)
DISABLE	High worked, Low not work.
NC	Not Connect

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maxim rating conditions for extended periods may affect device reliability.

Parameter		Rating	Unit
Supply Voltage		7.5	V
Input Voltage		(V-)-0.5 to (V+)+0.5	V
Storage Temperature Range		-65 to 150	°C
Junction Temperature		150	°C
Lead Temperature Range		260	°C
ESD	HBM, JEDEC: JESD22-A114	8	kV
	CDM, JEDEC: JESD22-C101	2	

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation to ensure optimal performance to the datasheet specifications. DIOO does not recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter	Rating	Unit
Supply Voltage	2.5 to 5.5	V
Input Voltage	0 to 5	V
Operating Temperature Range	-40 to 125	°C

Electrical Characteristics

Typical value: $V_{+}=5V$, $R_L=100k\Omega$ to $V_{+}/2$, $T_A = 25^{\circ}C$, unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
V _{OS}	Input Offset Voltage	T _A =25°C	-3.5	0.7	3.5	mV
I _B	Input Bias Current	-40°C≤T _A ≤125°C, V ₊ =2.5V to 5.5V		1	10	pA
I _{OS}	Input Offset Current	-40°C≤T _A ≤125°C, V ₊ =2.5V to 5.5V		1	10	pA
V _{CM}	Common Mode Voltage Range	V ₊ =5.5V	-0.1		5.6	V
CMRR	Common Mode Rejection Ratio	-40°C≤T _A ≤125°C, V _S = 5.5V, V _{CM} =-0.1V to 4V	75	90		dB
		-40°C≤T _A ≤125°C, V _S =5.5V, V _{CM} =-0.1V to 5.6V	66	90		dB
A _{OL}	Open Loop Voltage Gain	R _L =600Ω, V _O =0.15V to 4.85V	92	100		dB
		R _L =10KΩ, V _O =0.05V to 4.95V	100	110		dB
ΔV _{OS} /ΔT	Input Offset Voltage Drift	-40°C≤T _A ≤125°C		2.7		μV/°C
OUTPUT CHARACTERISTICS						
	Output Voltage Swing from Rail	R _L =600Ω -40°C≤T _A ≤125°C			0.1	V
		R _L =10kΩ -40°C≤T _A ≤125°C			0.015	
I _{OUT}	Output Current	V ₊ = 5V	45	48		mA
Ro	Closed Loop Output Impedance	F=100kHz, G=+1		2.6		Ω
POWER-DOWN DISABLE						
	Turn-On Time			6.2		nS
	Turn-Off Time			1.4		nS
	DISABLE Voltage Off				1.9	V
	DISABLE Voltage On		2			V
POWER SUPPLY						
	Operating Voltage Range		2.5		5.5	V
PSRR	Power Supply Rejection Ration		70	94		dB
I _S	Supply Current per Channel/Amp	V ₊ = 5V , -40°C≤T _A ≤125°C		350		μA
		V ₊ = 2.5V , -40°C≤T _A ≤125°C		320		
DYNAMIC PERFORMANCE						
GBP	Gain Bandwidth Product	R _L =10kΩ		6		MHz
SR	Slew Rate	R _L =600Ω, G=1, 2V Output Step		3.6		V/μs
t _s	Setting Time	R _L =600Ω, G=1, 2V Output Step			1	μs
NOISE PERFORMANCE						
THD	Total Harmonic Distortion	f=10kHz, 1V Output Step, R _L =600Ω and 100pF		0.015		%
e _n	Voltage Noise Density	f=1kHz, V ₊ = 5V		20		nV/√Hz
		f=10kHz, V ₊ = 5V		12		

Specifications subject to change without notice.

Typical Application

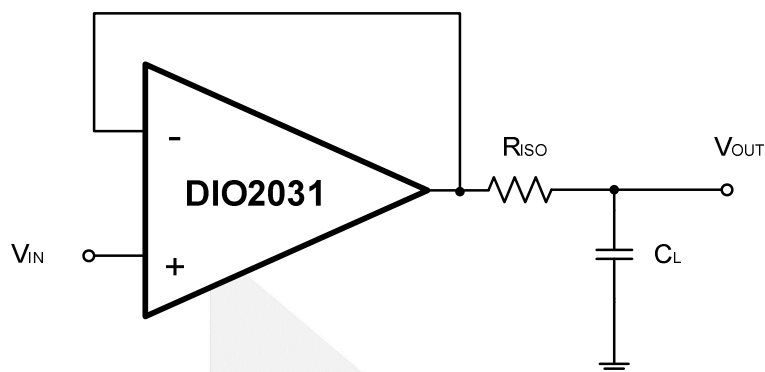


Figure 2 Indirectly Driving Heavy Capacitive Load

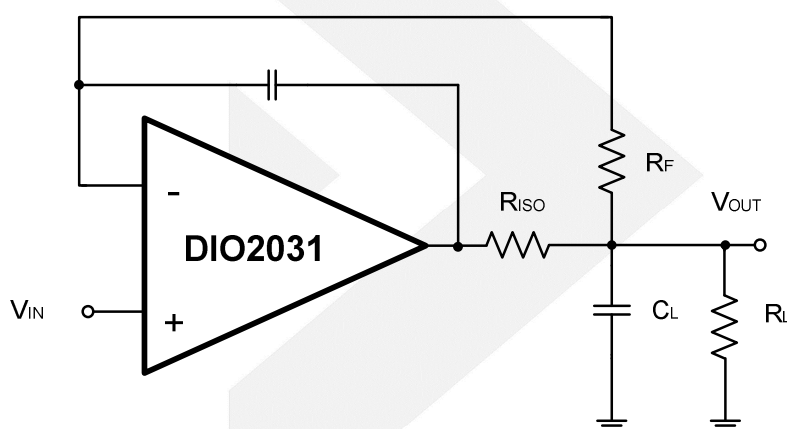


Figure 3 Indirectly Driving Heavy Capacitive Load with DC Accuracy

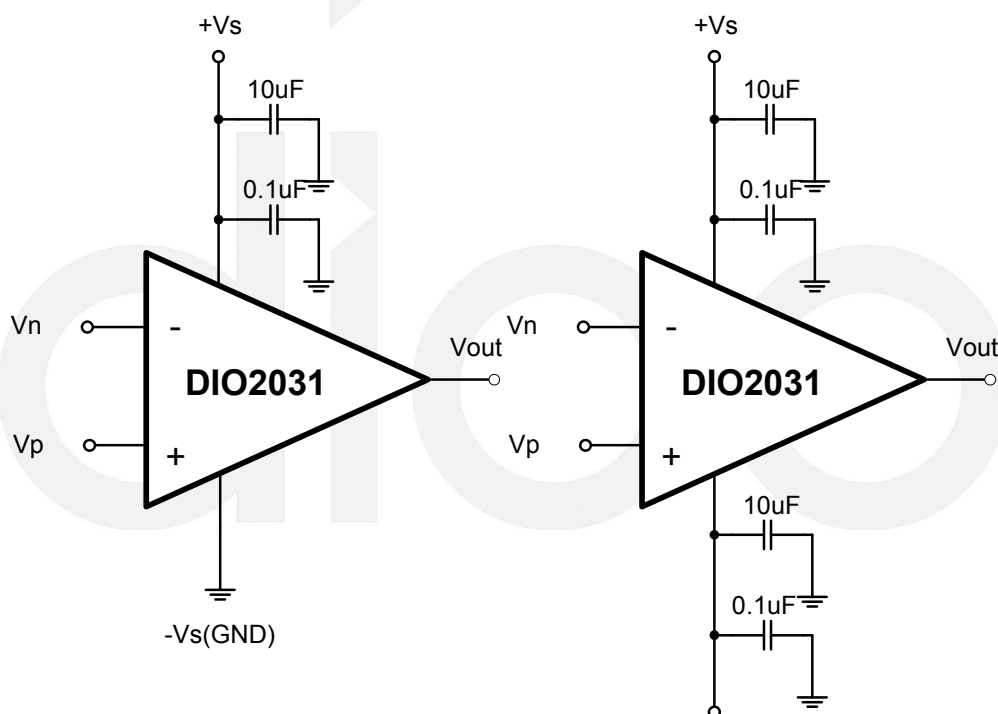
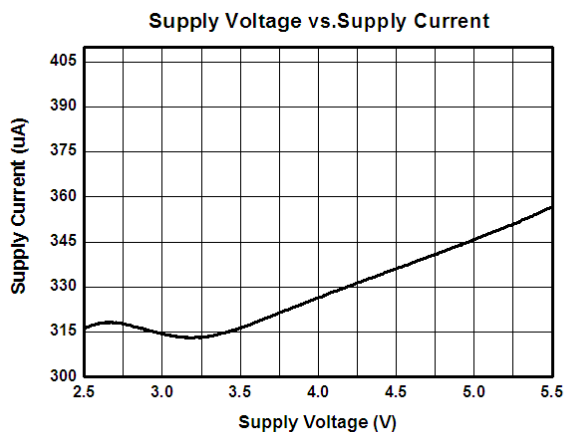


Figure 4 Amplifier with Bypass Capacitors

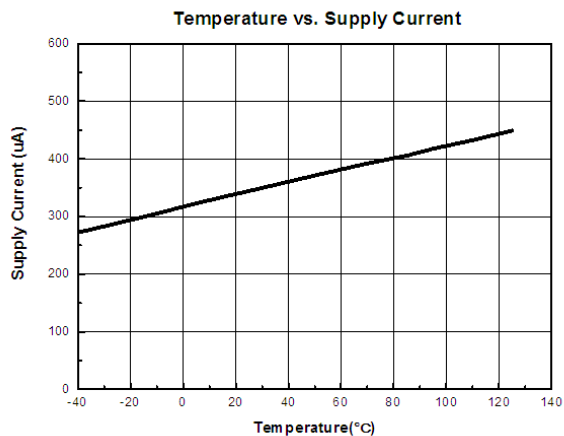
Typical Performance Characteristics

Typical value: $V_{+}=5V$, $R_L=100k\Omega$ to $V_{+}/2$, $T_A = 25^{\circ}C$, unless otherwise specified.

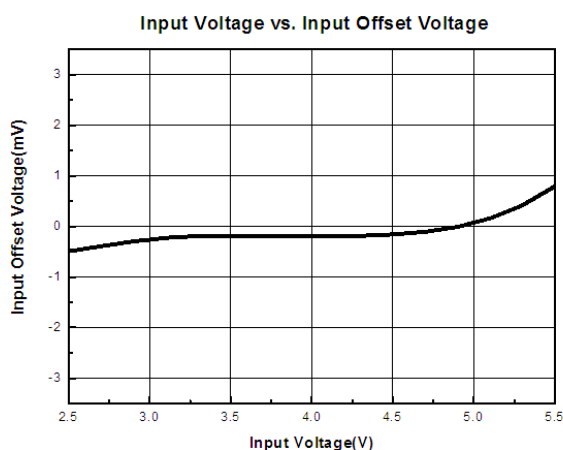
Supply Voltage vs. Supply Current



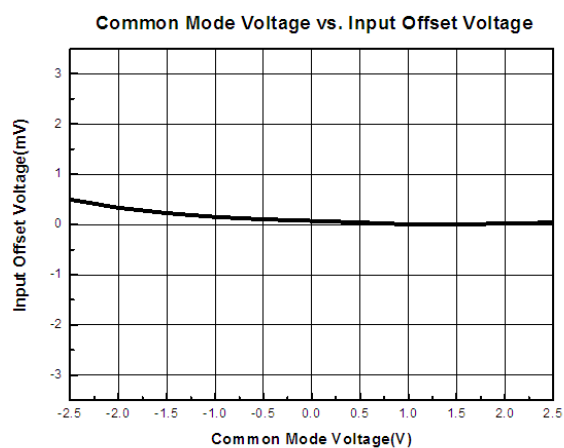
Temperature vs. Supply Current



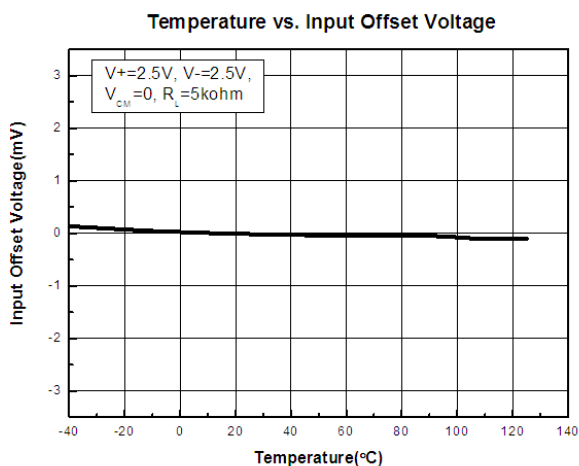
Input Voltage vs. Supply Current



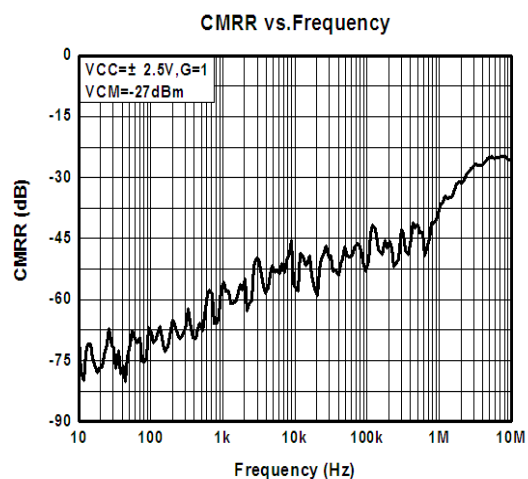
Common Mode Voltage vs. Input Offset Current



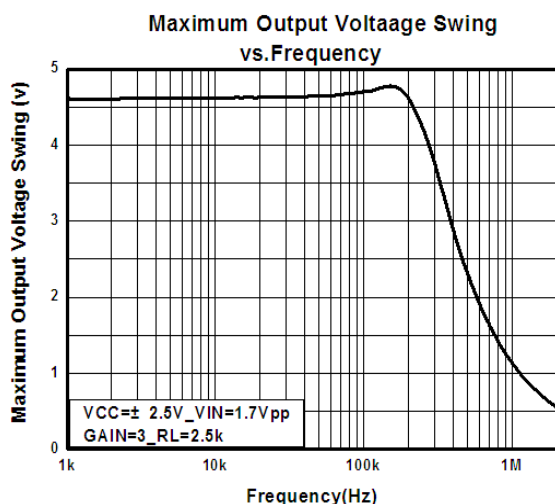
Temperature vs. Input Offset Voltage



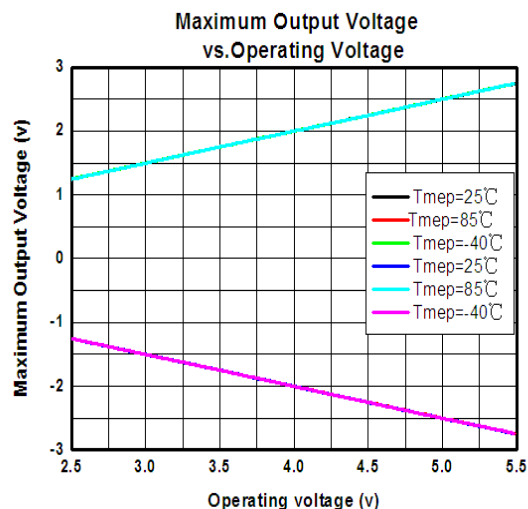
CMRR vs. Frequency



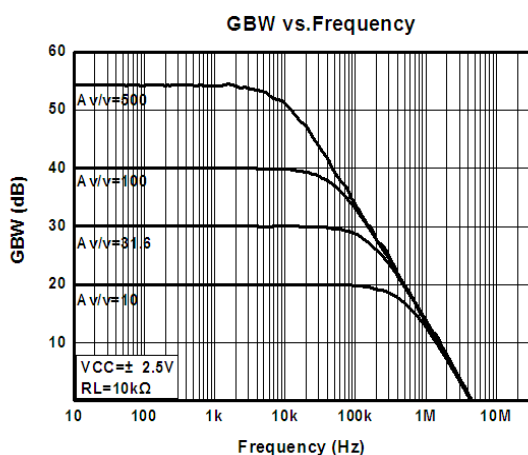
Maximum Output Voltage Swing vs. Frequency



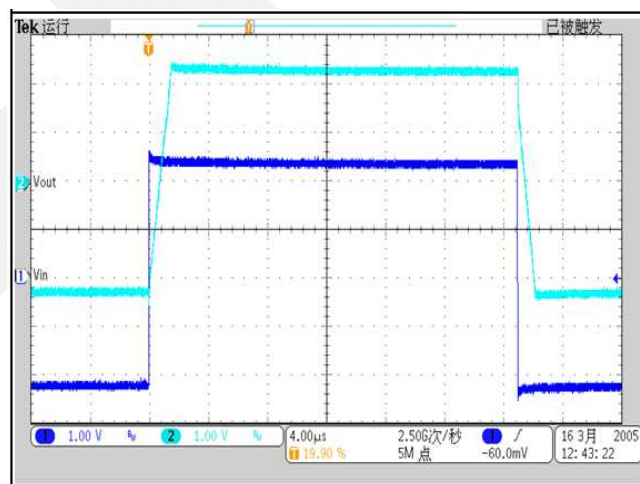
Maximum Output Voltage vs. Operating Voltage



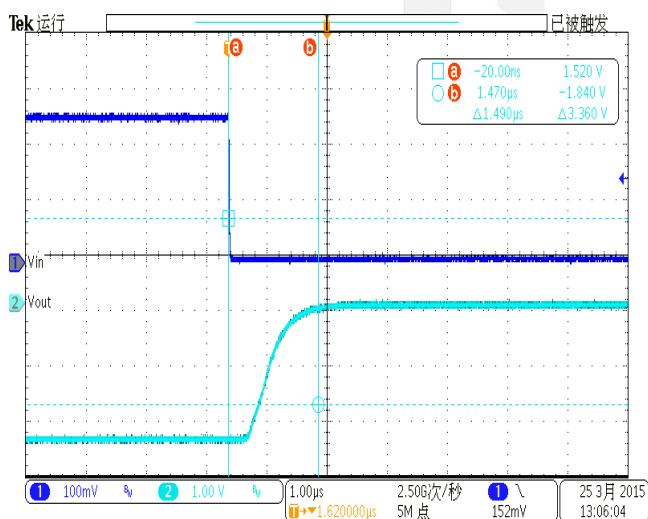
GBW vs. Frequency



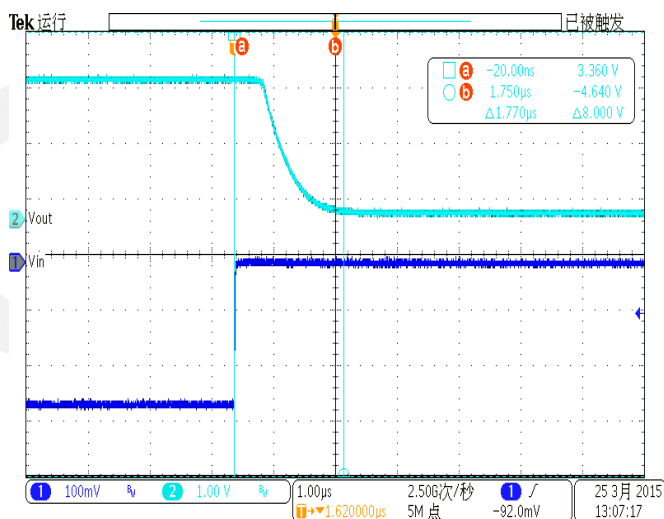
Slew Rate



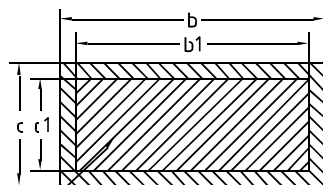
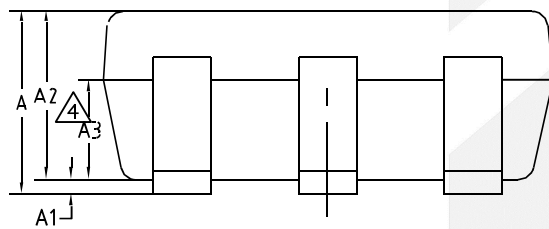
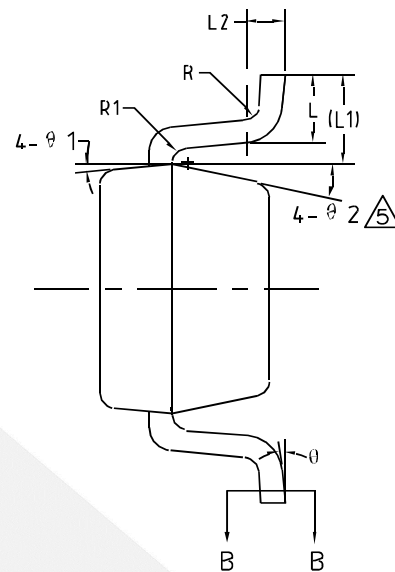
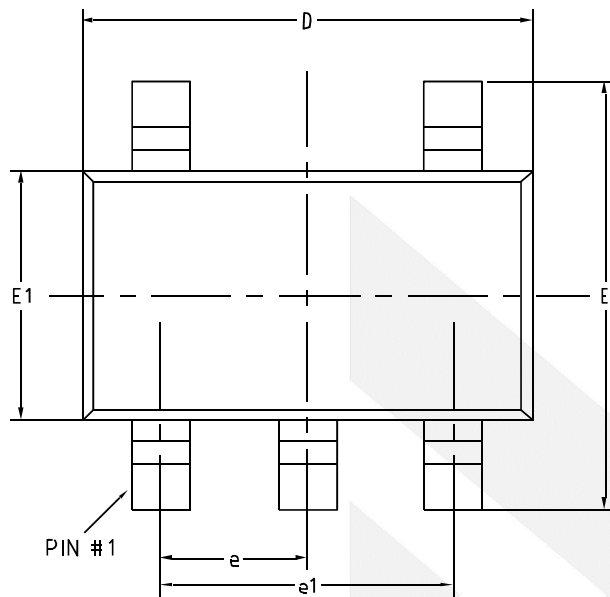
Over Load Recover(Positive)



Over Load Recover(Negative)



Physical Dimensions: SOT-23-5

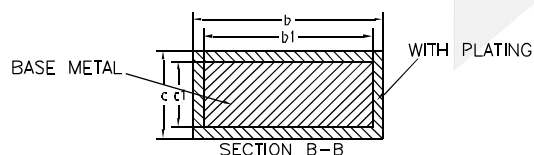
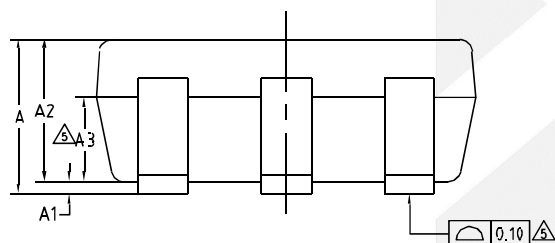
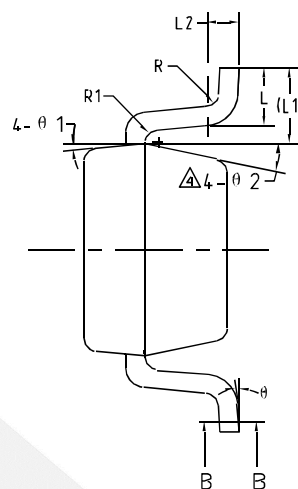
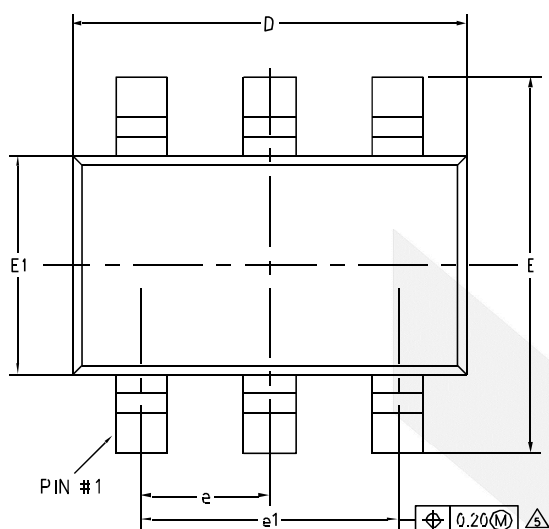


BASE METAL
SECTION B-B

COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	-	-	1.25
A1	0	-	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	-	0.50
b1	0.36	0.38	0.45
c	0.14	-	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59REF		
L2	0.25BSC		
R	0.10	-	-
R1	0.10	-	0.25
θ	0°	-	8°
θ1	3°	5°	7°
θ2	6°	-	14°

500μA, 6MHz, Rail-to-Rail I/O CMOS Operational Amplifiers

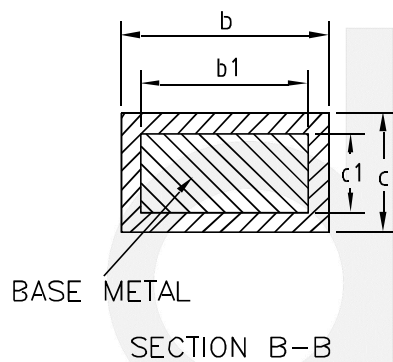
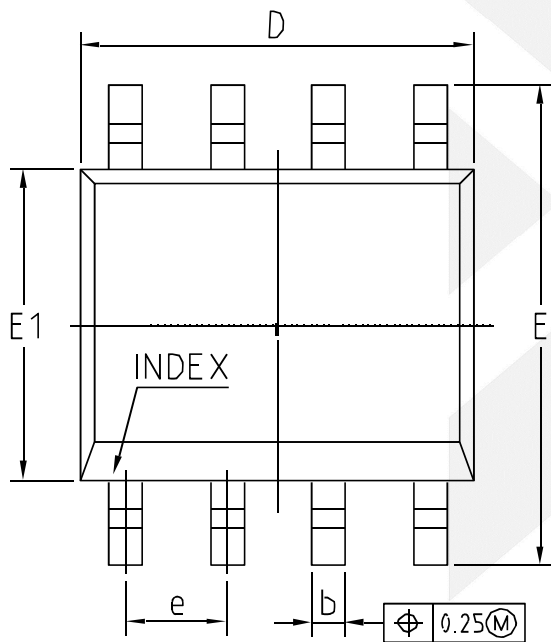
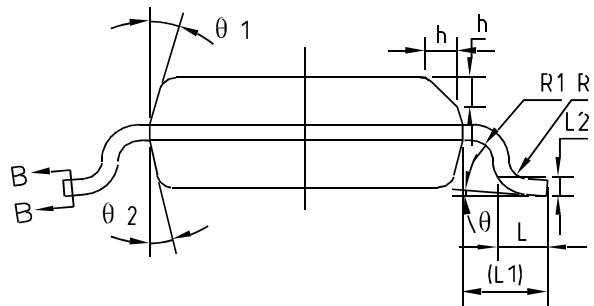
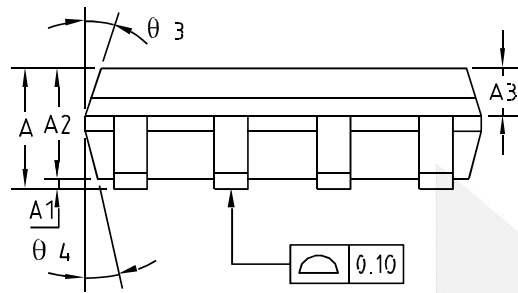
Physical Dimensions: SOT-23-6



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	-	-	1.25
A1	0	-	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	-	0.50
b1	0.36	0.38	0.45
c	0.14	-	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59REF		
L2	0.25BSC		
R	0.10	-	-
R1	0.10	-	0.25
θ	0°	-	8°
θ1	3°	5°	7°
θ2	6°	-	14°

500μA, 6MHz, Rail-to-Rail I/O CMOS Operational Amplifiers

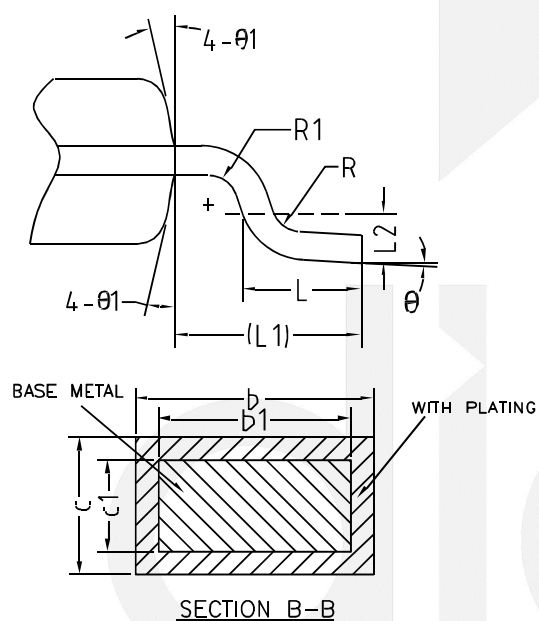
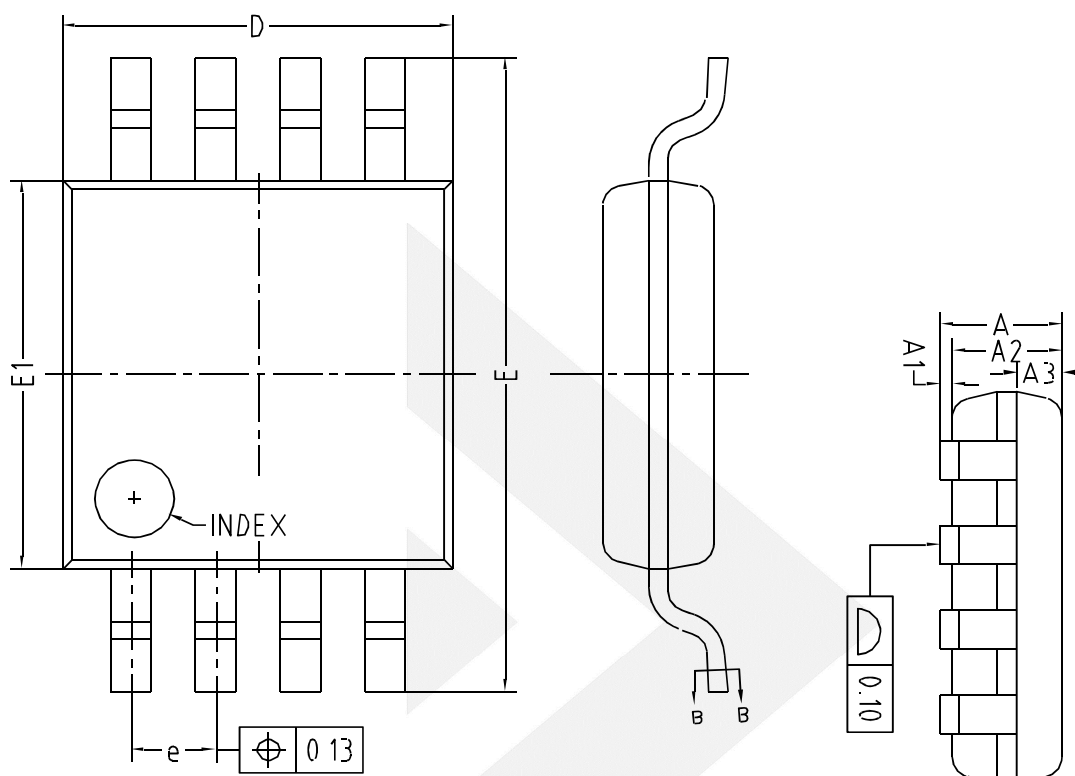
Physical Dimensions: SOIC-8



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	1.35	1.55	1.75
A1	0.10	0.15	0.25
A2	1.25	1.40	1.65
A3	0.50	0.60	0.70
b	0.38	-	0.51
b1	0.37	0.42	0.47
c	0.17	-	0.25
c1	0.17	0.20	0.23
D	4.80	4.90	5.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.27BSC		
L	0.45	0.60	0.80
L1	1.04REF		
L2	0.25BSC		
R	0.07	-	-
R1	0.07	-	-
h	0.30	0.40	0.50
θ	0°	-	8°
θ1	15°	17°	19°
θ2	11°	13°	15°
θ3	15°	17°	19°
θ4	11°	13°	15°

500μA, 6MHz, Rail-to-Rail I/O CMOS Operational Amplifiers

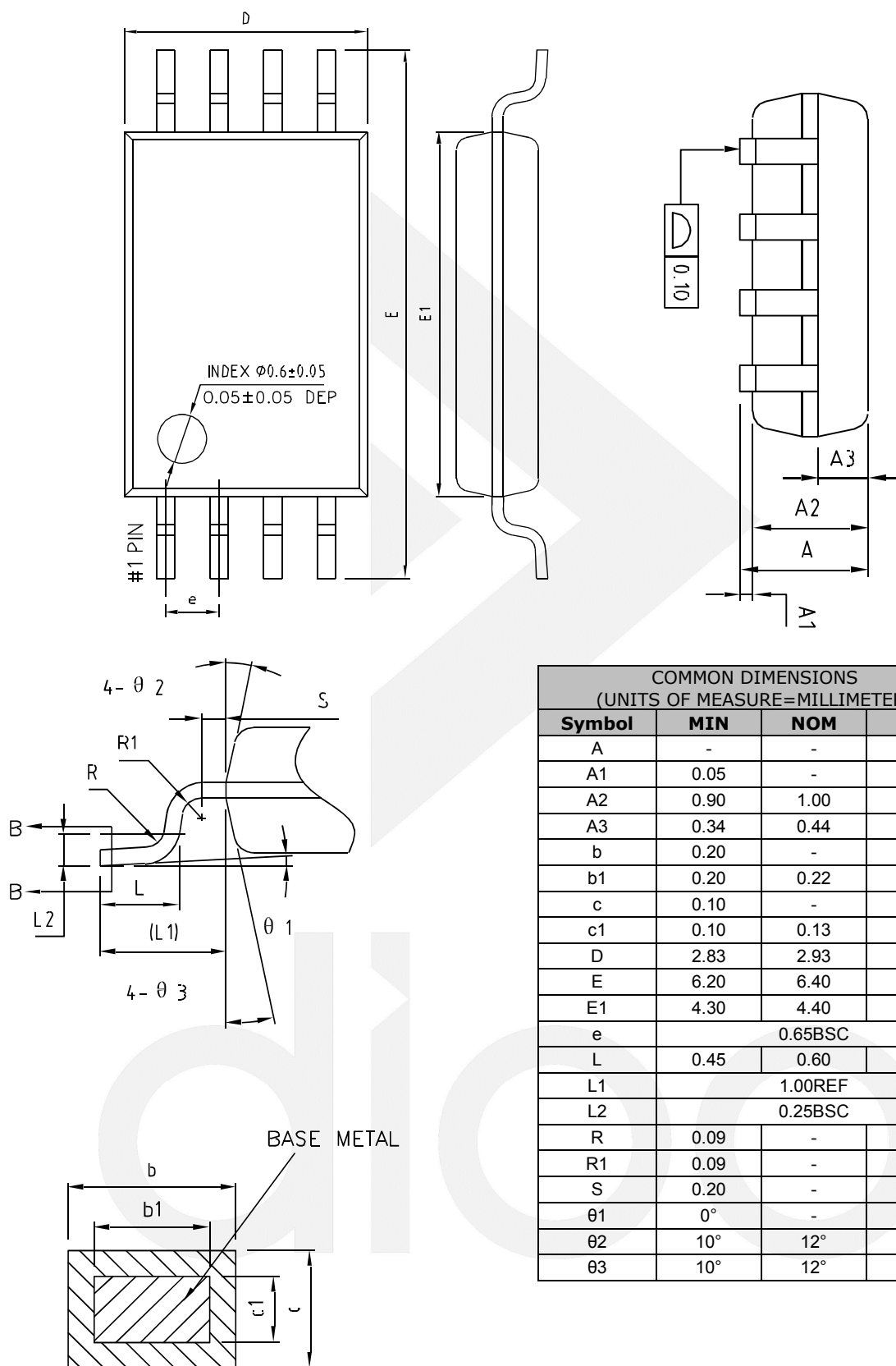
Physical Dimensions: MSOP-8



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	-	-	1.10
A1	0	-	0.15
A2	0.75	0.85	0.95
A3	0.25	0.35	0.39
b	0.28	-	0.37
b1	0.27	0.30	0.33
c	0.15	-	0.20
c1	0.14	0.15	0.16
D	2.90	3.00	3.10
E	4.70	4.90	5.10
E1	2.90	3.00	3.10
e	0.55	0.65	0.75
L	0.40	0.60	0.80
L1	0.95REF		
L2	0.25BSC		
R	0.07	-	-
R1	0.07	-	-
Θ	0°	-	8°
Θ1	9°	12°	15°

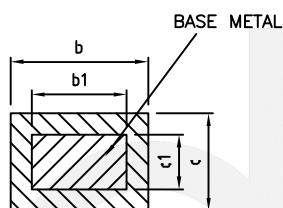
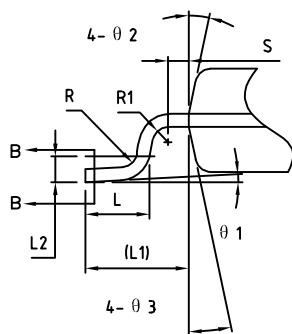
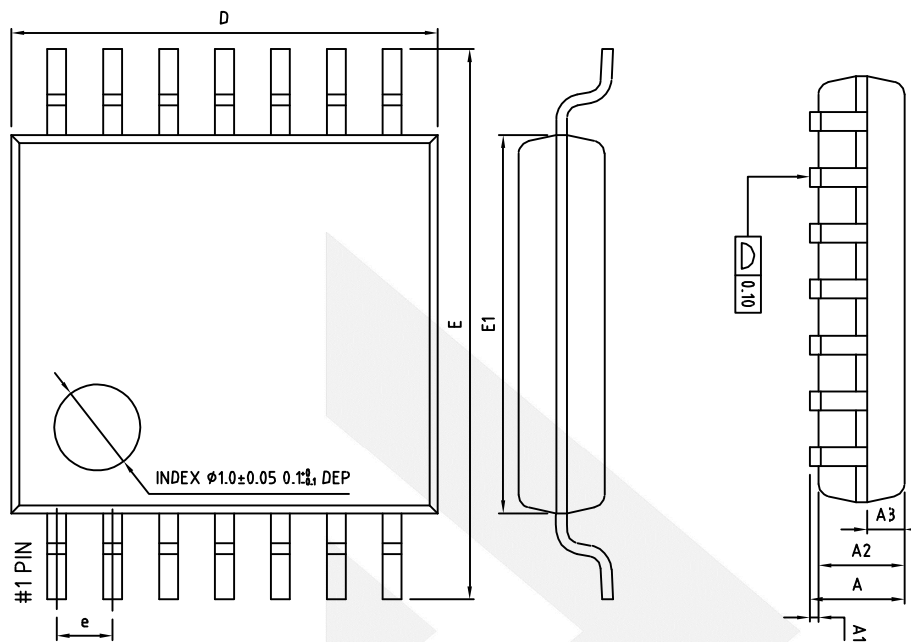
Physical Dimensions: TSSOP-8

500μA, 6MHz, Rail-to-Rail I/O CMOS Operational Amplifiers



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	-	-	1.20
A1	0.05	-	0.15
A2	0.90	1.00	1.05
A3	0.34	0.44	0.54
b	0.20	-	0.28
b1	0.20	0.22	0.24
c	0.10	-	0.19
c1	0.10	0.13	0.15
D	2.83	2.93	3.03
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65BSC		
L	0.45	0.60	0.75
L1	1.00REF		
L2	0.25BSC		
R	0.09	-	-
R1	0.09	-	-
S	0.20	-	-
$\theta 1$	0°	-	8°
$\theta 2$	10°	12°	14°
$\theta 3$	10°	12°	14°

Physical Dimensions: TSSOP-14



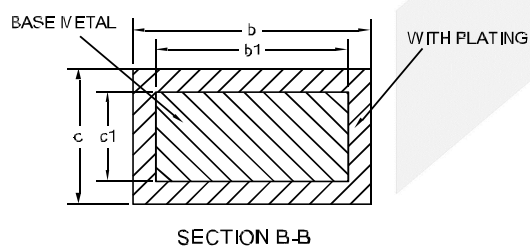
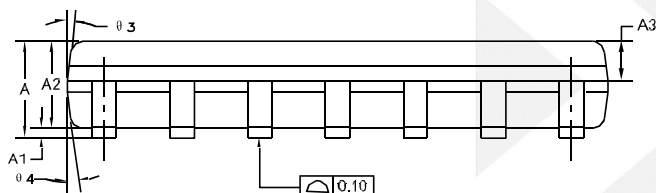
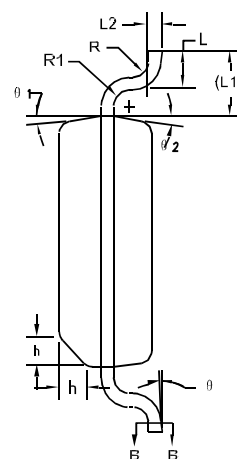
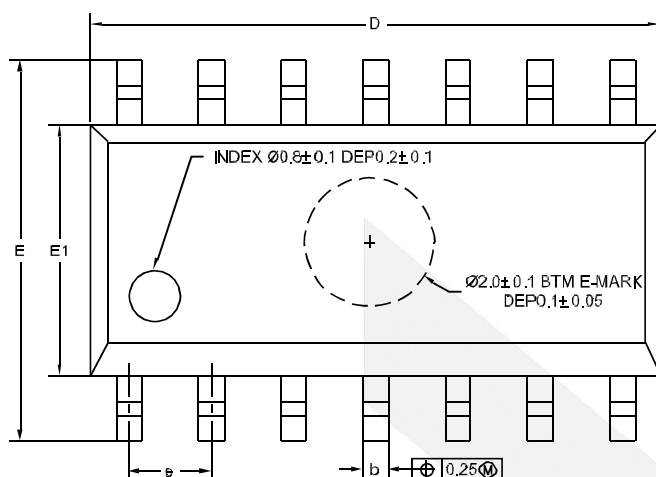
SECTION B-B

COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	-	-	1.20
A1	0.05	-	0.15
A2	0.90	1.00	1.05
A3	0.34	0.44	0.54
b	0.20	-	0.28
b1	0.20	0.22	0.24
c	0.10	-	0.19
c1	0.10	0.13	0.15
D	4.86	4.96	5.06
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65BSC		
L	0.45	0.60	0.75
L1	1.00REF		
L2	0.25BSC		
R	0.09	-	-
R1	0.09	-	-
S	0.20	-	-
$\theta 1$	0°	-	8°
$\theta 2$	10°	12°	14°
$\theta 3$	10°	12°	14°

500 μ A, 6MHz, Rail-to-Rail I/O CMOS Operational Amplifiers

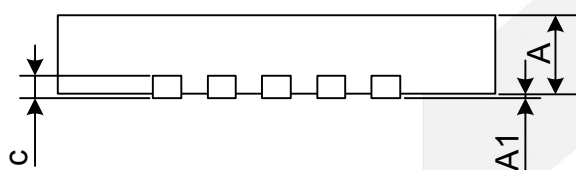
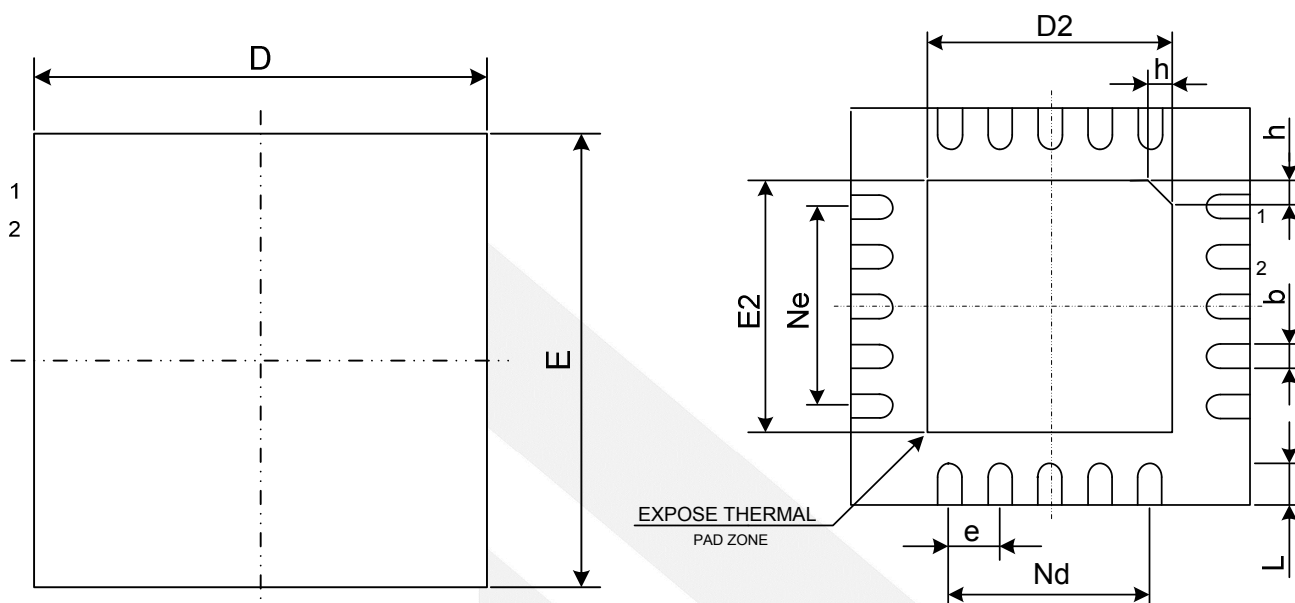
Physical Dimensions: SOIC-14

500μA, 6MHz, Rail-to-Rail I/O CMOS Operational Amplifiers



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	1.35	1.60	1.75
A1	0.10	0.15	0.25
A2	1.25	1.45	1.65
A3	0.55	0.65	0.75
b	0.36	-	0.49
b1	0.35	0.40	0.45
c	0.17	-	0.25
c1	0.17	0.20	0.23
D	8.53	8.63	8.73
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.27BSC		
L	0.45	0.60	0.80
L1	1.04REF		
L2	0.25BSC		
R	0.07	-	-
R1	0.07	-	-
h	0.30	0.40	0.50
θ	0°	-	8°
θ1	6°	8°	10°
θ2	6°	8°	10°
θ3	5°	7°	9°
θ4	5°	7°	9°

Physical Dimensions: QFN-20



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	-	0.02	0.05
b	0.18	0.25	0.30
c	0.18	0.20	0.25
D	3.90	4.00	4.10
D2	2.55	2.65	2.75
e	0.50BSC		
Ne	2.00BSC		
Nd	2.00BSC		
E	3.90	4.00	4.10
E2	2.55	2.65	2.75
L	0.35	0.40	0.45
h	0.30	0.35	0.40
L/F 载体尺寸(mil)	114X114		

500μA, 6MHz, Rail-to-Rail I/O CMOS Operational Amplifiers

CONTACT US

Dioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as, cell phone, handheld products, laptop, and medical equipment and so on. Dioo's product families include analog signal processing and amplifying, LED drivers and charger IC. Go to <http://www.dioo.com> for a complete list of Dioo product families.

For additional product information, or full datasheet, please contact with our Sales Department or Representatives.